MATERIALS LETTERS EDITORS NAMED

MRS appoints Associate Editors to new letters journal

As part of the Society's affiliation with the new journal. Materials Letters, it appoints a majority of Associate Editors to the journal's Editorial Board. (As the Bulletin has reported earlier, the two Principal Editors of the journal are among the MRS's leadership.) Some 28 members constitute initial the representatives.

These scientists will serve staggered terms of two, three or four years, so that in the future a third of the Editorial Board will come up for appointment each year.

Potential contributors to Materials Letters are invited to submit contributions to Associate Editors, as well as the journal's Principal Editors.

The editors, their affiliation and area(s) of expertise are:

B.R. Appleton

Oak Ridge National Laboratory Laser processing; ion-solid interactions

Alan E. Bell

IBM-San Jose

Laser annealing; thin film optics

L.A. Boatner

Oak Ridge National Laboratory Nuclear waste disposal; crystal growth; **EPR**

L.L. Chang

IBM-Yorktown Heights

MBE; superlattice and heterostructures

James W. Corbett

SUNY-Albany

Defects in semiconductors

James C.C. Fan

MIT-Lincoln Lab

Semiconductor materials; devices: material processing

Prof. Seijiro Furukuwa

Tokyo Institute of Technology

Ion implantation; epitaxial growth: beam annealing

Dr. James F. Gibbons

Stanford

Ion implantation; laser annealing

B.C. Giessen

Northeastern U.

Rapid solidification rate processing; metallic glasses; alloy phases

> Society appoints twenty-eight Associate Editors to Materials Letters

Dr. Carol M. Jantzen

Du Pont-Savannah

Nuclear waste corrosion management

Elton N. Kaufmann

U. Calif.-Livermore

Nuclear spectroscopic methods; ion beam analysis; surface modification of materials

Dr. Philipp H. Klein

Naval Research Lab

Halides; crystal growth; IR materials

Prof. Kamil Klier

Lehigh University

Characterization catalysts; catalysis

Werner Lutze

Hahn-Meitner-Institut

Nuclear waste forms and materials properties

Farrel W. Lytle

Boeing

EXAFS: structure catalysts: amorphous materials

Prof. J.W. Mayer

Cornell University

Silicide formation: ion beam modification of materials; thin film reactions

P.A. Montana

West Virginia U.

Materials for coal processing: coal

conversion (catalysis); metal clusters characterization

Prof. B.L. Mordike

Technische Uni. Clausthal

Rapid solidification; deformation; composite materials

J.C. Phillips

Bell Labs-Murray Hill

Theory of chemical bonding in solids; network glasses; amorphous semiconductors

S. Thomas Picraux

Sandia National Lab

Ion beam modification of materials; ion implantation

Prof. Della M. Roy

Penn State University

and Cement concrete: ceramic processing; nuclear waste management

George A. Rozgonvi

No. Carolina State U.

Semiconductor defects: device processing

F.W. Saris

Institute for Atomic and Molecular **Physics**

Modification and analysis of materials with beams of ions/photons

Frans Spaegen

Harvard

Phase transformations; metallic glasses

John A. Stone

Du Pont-Savannah

Nuclear waste management and disposal

Earl R. Thompson

United Technologies

Composite materials: superallovs: powder metallurgy

C.W. White

Oak Ridge National Lab

Laser annealing; ion implantation

William B. White

Penn State University

Crystal chemistry; ceramic processing; nuclear waste materials; infrared and raman spectroscopy